

# PJE8401

## 20V P-Channel Enhancement Mode MOSFET

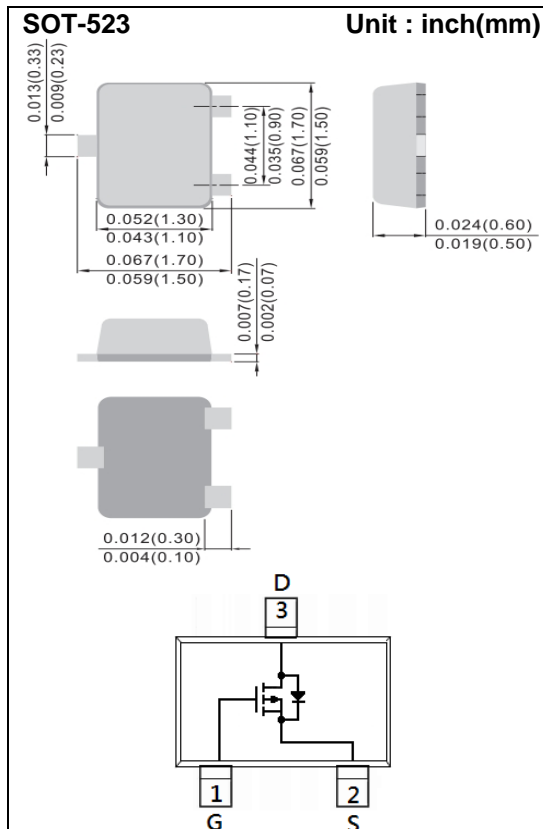
<b>Voltage</b>	<b>-20 V</b>	<b>Current</b>	<b>-0.9A</b>
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### Features

- $R_{DS(ON)}$  ,  $V_{GS}@-4.5V$  ,  $I_D@-0.9A < 130m\Omega$
- $R_{DS(ON)}$  ,  $V_{GS}@-2.5V$  ,  $I_D@-0.6A < 160m\Omega$
- $R_{DS(ON)}$  ,  $V_{GS}@-1.8V$  ,  $I_D@-0.4A < 210m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

### Mechanical Data

- Case: SOT-523 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.00007 ounces, 0.002 grams
- Marking: E01



## Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	-20	V
Gate-Source Voltage		V <sub>GS</sub>	±12	V
Continuous Drain Current		I <sub>D</sub>	-0.9	A
Pulsed Drain Current		I <sub>DM</sub>	-3.6	A
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	300	mW
	Derate above 25°C		2.4	mW/°C
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55~150	°C
Typical Thermal resistance		R <sub>θJA</sub>	417	°C/W
- Junction to Ambient <sup>(Note 3)</sup>				



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## Electrical Characteristics ( $T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-20	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-0.4	-0.69	-1.2	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-0.9A	-	110	130	mΩ
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-0.6A	-	130	160	
		V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-0.4A	-	160	210	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V, V <sub>GS</sub> =0V	-	-0.01	-1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±12V, V <sub>DS</sub> =0V	-	±10	±100	nA
Dynamic						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =-10V, I <sub>D</sub> =-0.9A, V <sub>GS</sub> =-4.5V (Note 1,2)	-	5.4	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	0.7	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	1.4	-	
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =-10V, V <sub>GS</sub> =0V, f=1.0MHZ	-	416	-	pF
Output Capacitance	C <sub>oss</sub>		-	43	-	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	32	-	
Switching						
Turn-On Delay Time	td <sub>(on)</sub>	V <sub>DD</sub> =-10V, I <sub>D</sub> =-0.9A, V <sub>GS</sub> =-4.5V, R <sub>G</sub> =6Ω (Note 1,2)	-	4	-	ns
Turn-On Rise Time	tr			27	-	
Turn-Off Delay Time	td <sub>(off)</sub>			78	-	
Turn-Off Fall Time	tf			45	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I <sub>S</sub>	---	-	-	-0.4	A
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-1A, V <sub>GS</sub> =0V		-0.8	-1.2	V

### NOTES :

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
4. The maximum current rating is package limited

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## TYPICAL CHARACTERISTIC CURVES

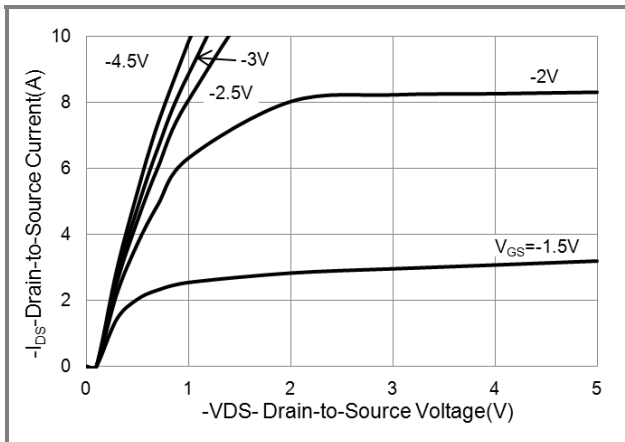


Fig.1 On-Region Characteristics

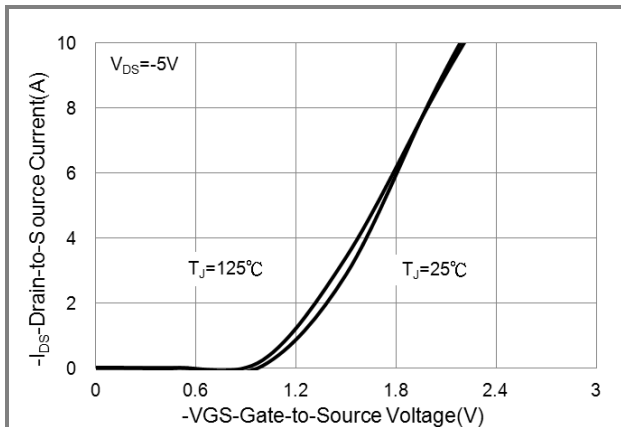


Fig.2 Transfer Characteristics

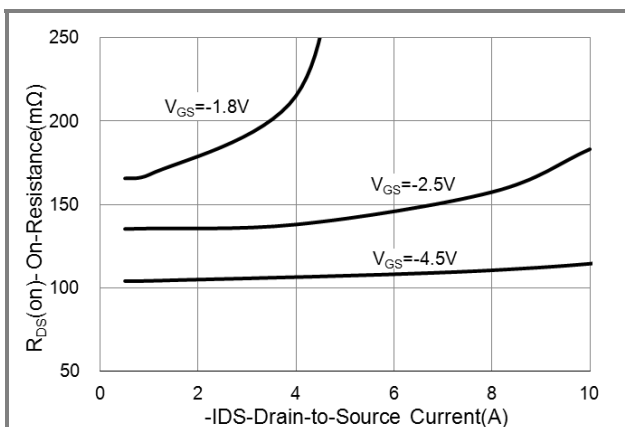


Fig.3 On-Resistance vs. Drain Current

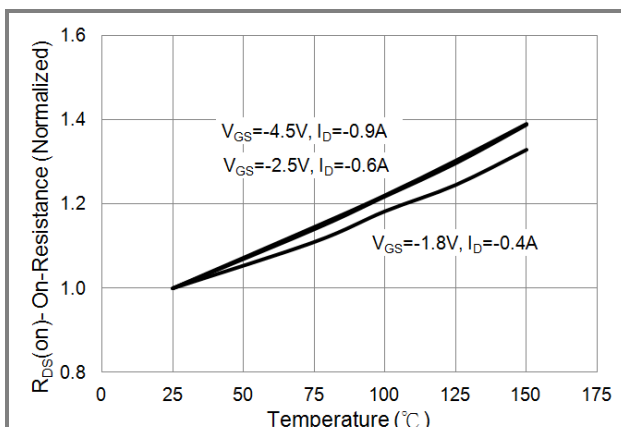


Fig.4 On-Resistance vs. Junction temperature

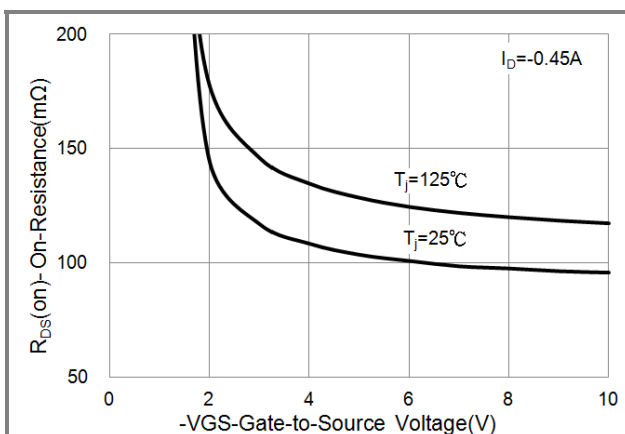


Fig.5 On-Resistance Variation with VGS.

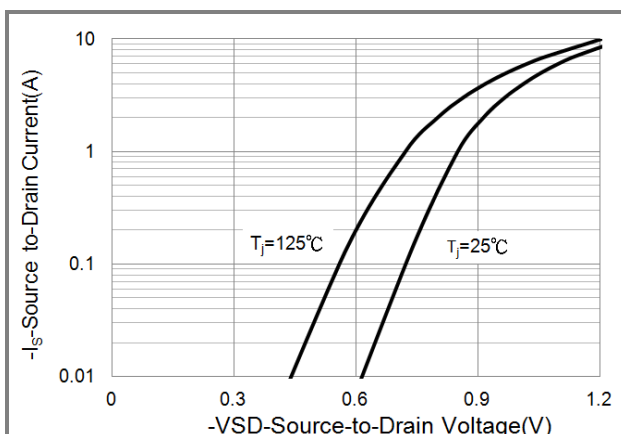


Fig.6 Body Diode Characteristics



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## TYPICAL CHARACTERISTIC CURVES

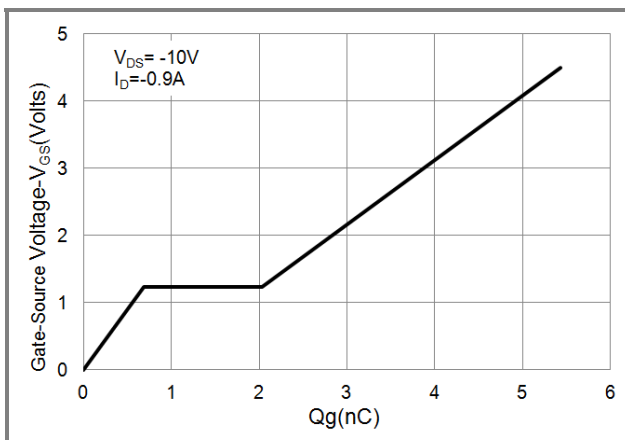


Fig.7 Gate-Charge Characteristics

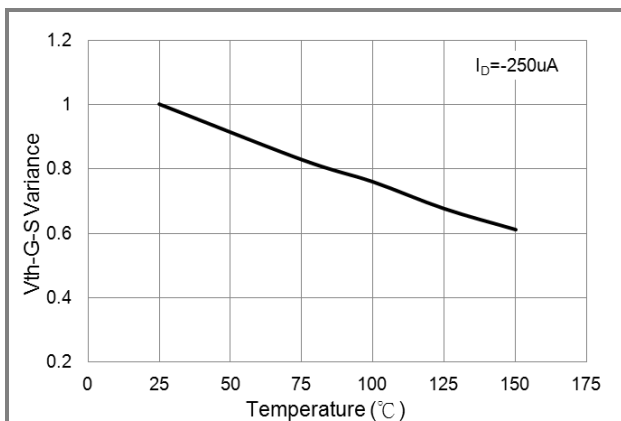


Fig.8 Threshold Voltage Variation with Temperature

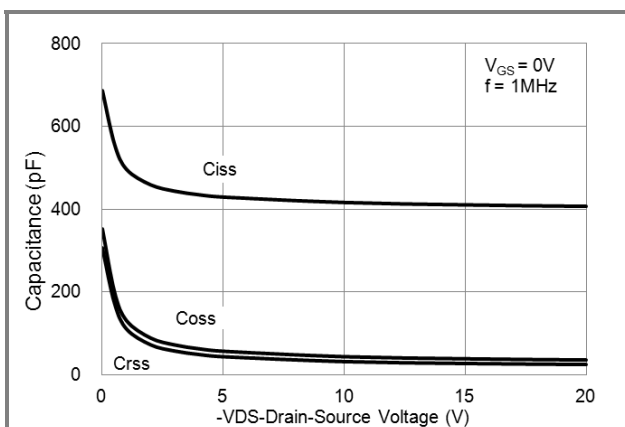


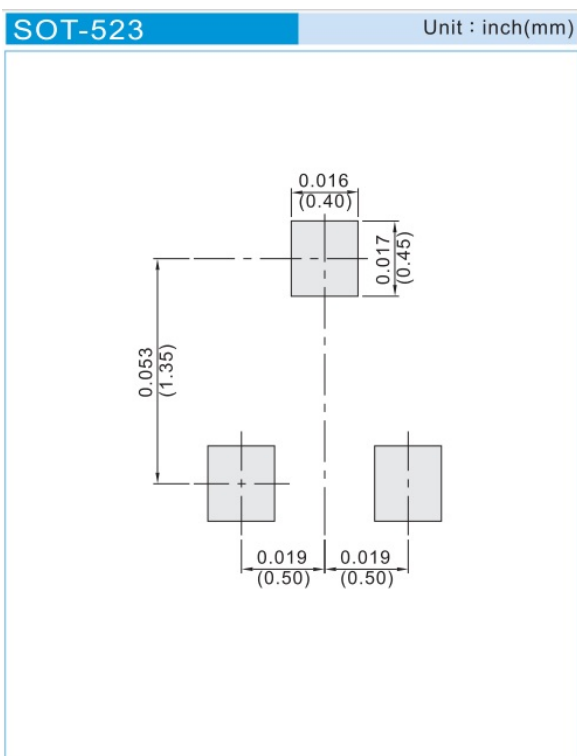
Fig.9 Capacitance vs. Drain-Source Voltage

# PJE8401

## PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJE8401_R1_00001	SOT-523	4K pcs / 7" reel	E01	Halogen free

## MOUNTING PAD LAYOUT





## PJE8401

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